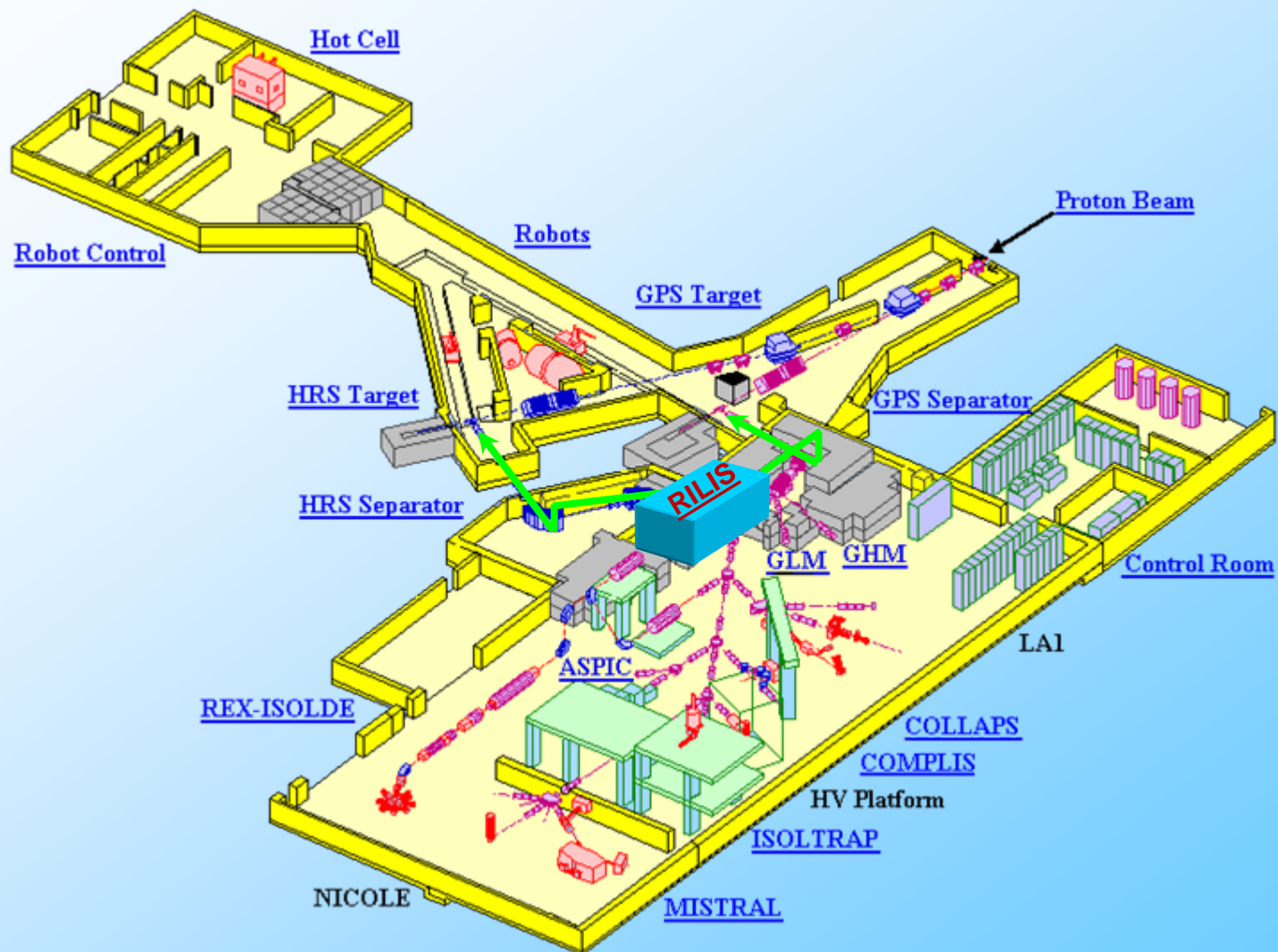


# ISOLDE RILIS: upgrade and development report

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# RILIS at ISOLDE Facility



# RILIS ion beams

Ion beams of 29 elements are produced at RILIS

elements available at ISOLDE LIS																			
1 H	ionization scheme tested																2 He		
3 Li	4 Be	ionization scheme untested												5 B	6 C	7 N	8 O	9 F	10 Ne
11 Na	12 Mg													13 Al	14 Si	15 P	16 S	17 Cl	18 Ar
19 K	20 Ca	21 Sc	22 Ti	23 V	24 Cr	25 Mn	26 Fe	27 Co	28 Ni	29 Cu	30 Zn	31 Ga	32 Ge	33 As	34 Se	35 Br	36 Kr		
37 Rb	38 Sr	39 Y	40 Zr	41 Nb	42 Mo	43 Tc	44 Ru	45 Rh	46 Pd	47 Ag	48 Cd	49 In	50 Sn	51 Sb	52 Te	53 I	54 Xe		
55 Cs	56 Ba	57 La	72 Hf	73 Ta	74 W	75 Re	76 Os	77 Ir	78 Pt	79 Au	80 Hg	81 Tl	82 Pb	83 Bi	84 Po	85 At	86 Rn		
87 Fr	88 Ra	89 Ac	104 Rf	105 Ha	106 Sg	107 Ns	108 Hs	109 Mt	110	111	112								

# Upgrade of RILIS laser system

Replacement of CVL by  
SSL

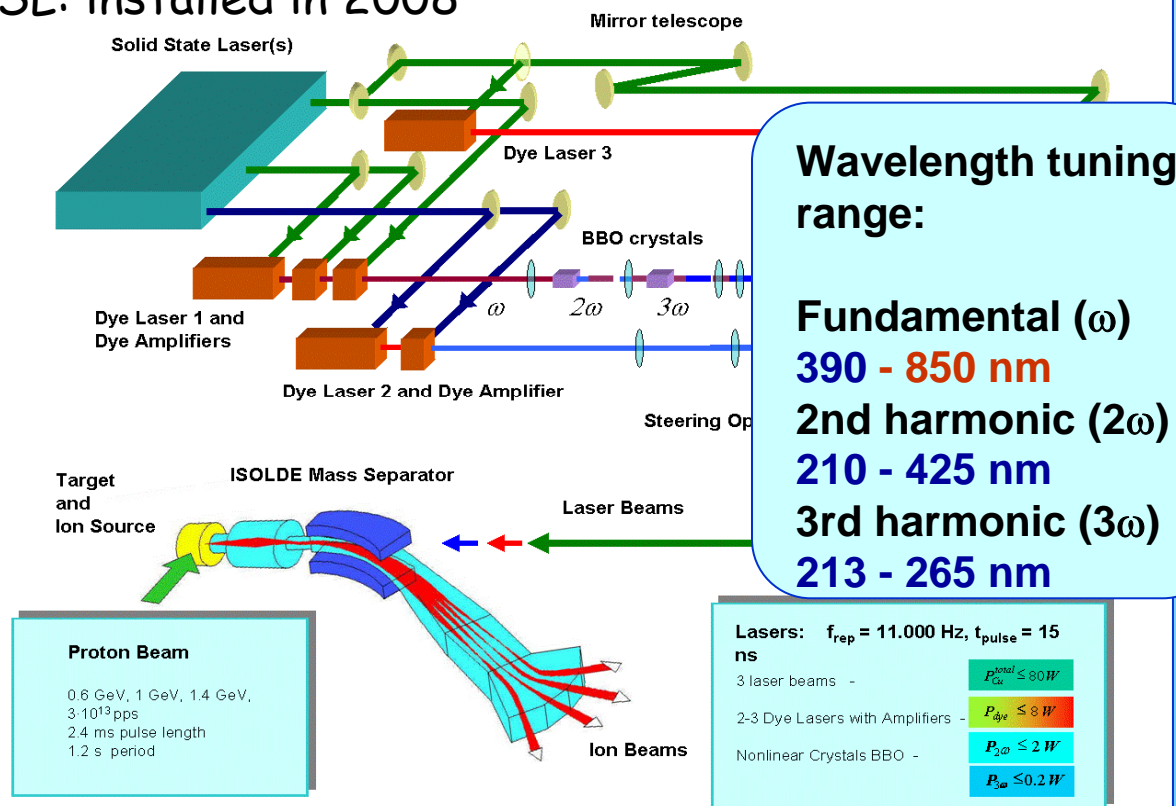
## Advantages:

- Better beam quality
- Stability of operation
- Spectral coverage UV-NIR without gaps

## Complications:

- New ionization schemes are needed (Mn, Au)
- Service by manufacturer only

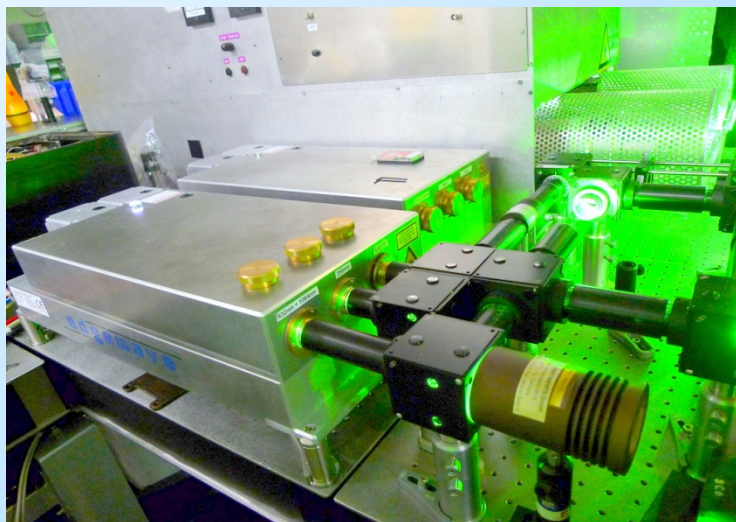
SSL: installed in 2008



# New Nd:YAG lasers at ISOLDE RILIS

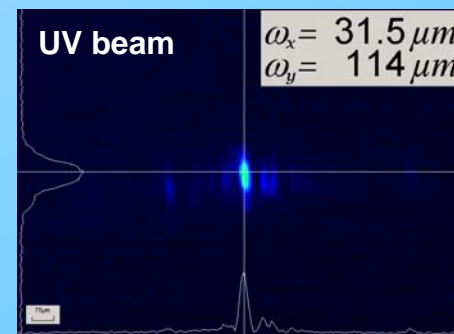
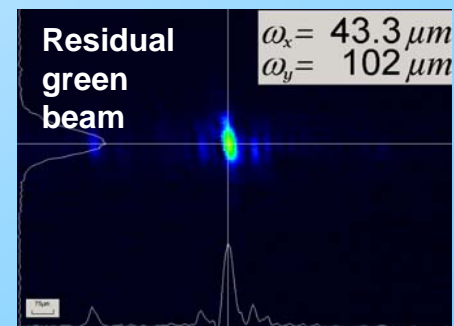
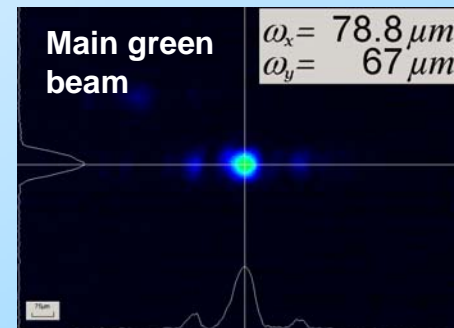
Copper Vapor Lasers are replaced by Diode Pumped Solid State Nd:YAG Lasers

- Two lasers are available:
- one in use, second as a backup



Laser generates 3 beams at 10 kHz:

- Main green beam - 532nm, 70-80 W, 8 ns
- Residual green beam - 532 nm, 12-28 W, 9 ns
- UV beam - 355 nm, 18-20 W, 11 ns





# SSL implementation in RILIS room

CVL  
amplifiers

Dye lasers

SSL power supply  
and chiller

CVL oscillator

CVL power  
supply



SSL laser  
systems



# SSL use: enhancements and current limitations

elements available at ISOLDE LIS

ionization scheme tested

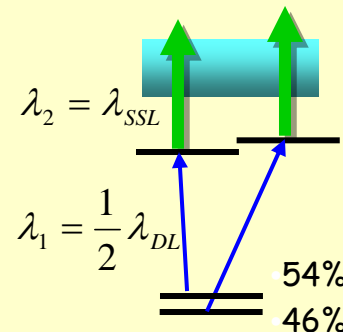
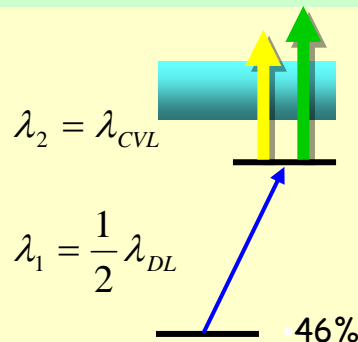
H	1
Li	3
Na	11
K	19
Rb	37
Cs	55
Fr	87
Be	4
Mg	12
Ca	20
Sr	38
Ba	56
Ra	88

He	2
Ne	10
Ar	18
Kr	36
Xe	54
Rn	86

Ce
Th

- Good example: **Gallium**
- ( used in 2008 and 2009 for COLLAPS)

- Two dye lasers were applied at 1<sup>st</sup> step of excitation - >2x improvement
- More power could be delivered to HRS target at the 2<sup>nd</sup> step of excitation



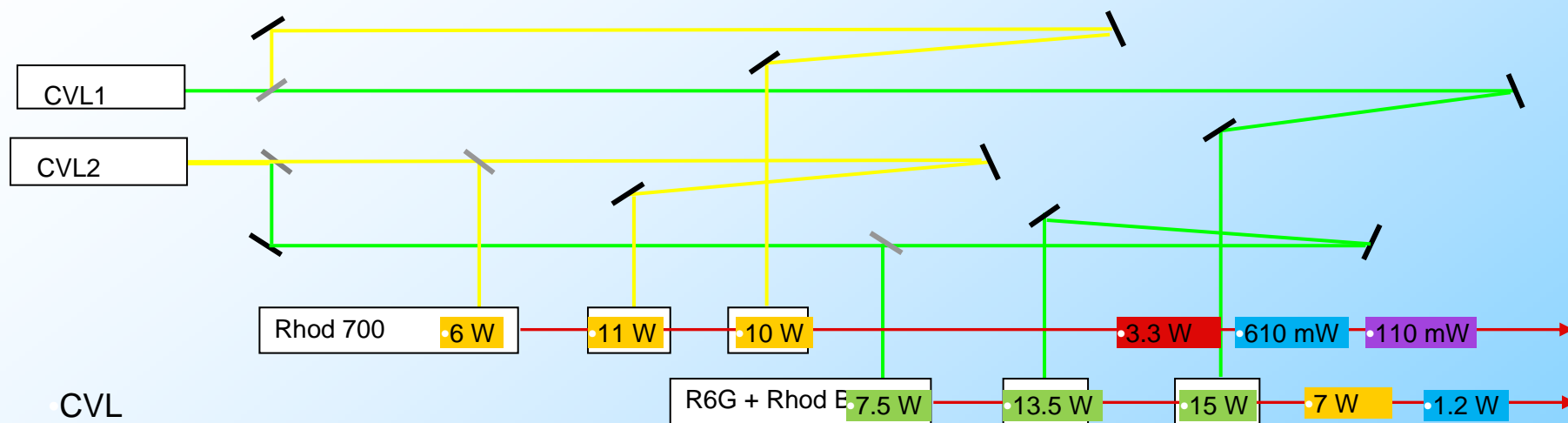
11 or 578 nm

ver

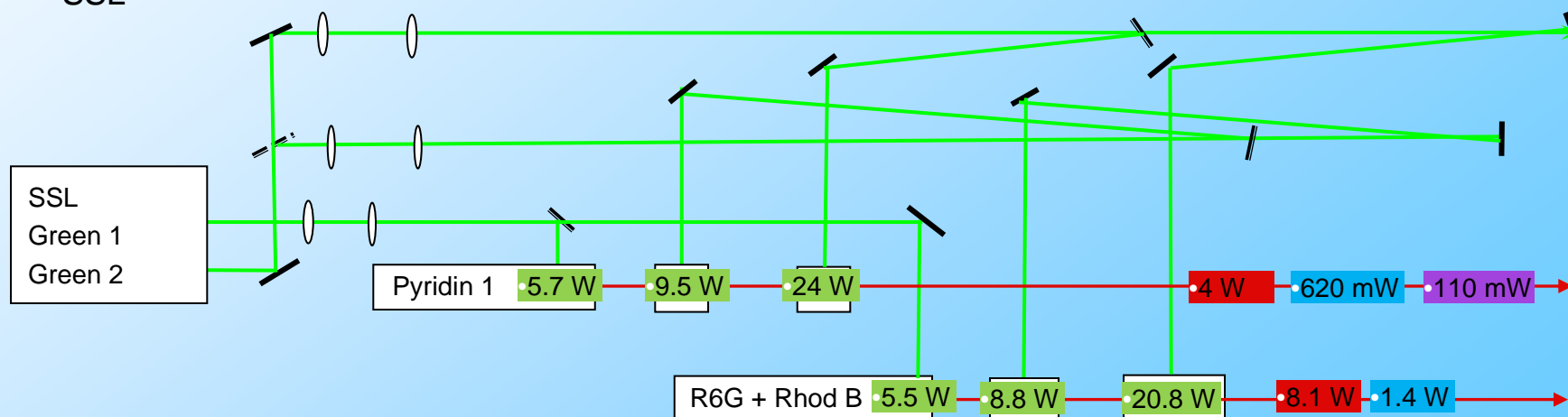
(Mn)

- Need for a < 540 nm fundamental wavelength.

# New beam set-up for Be ionization



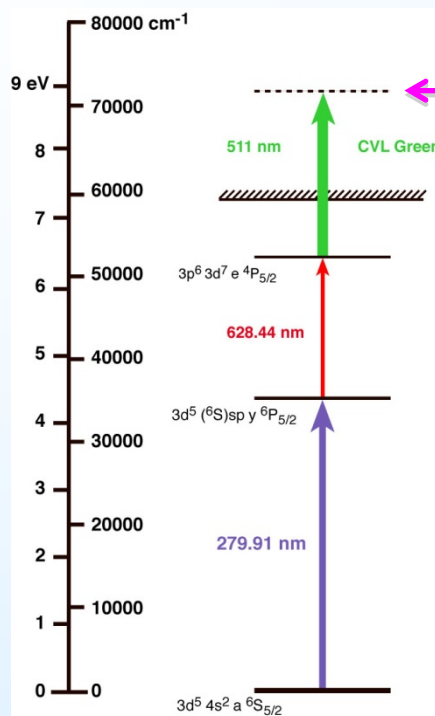
SSL







# A new RILIS scheme for manganese - LARIS result

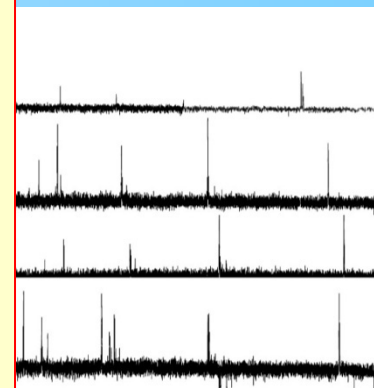
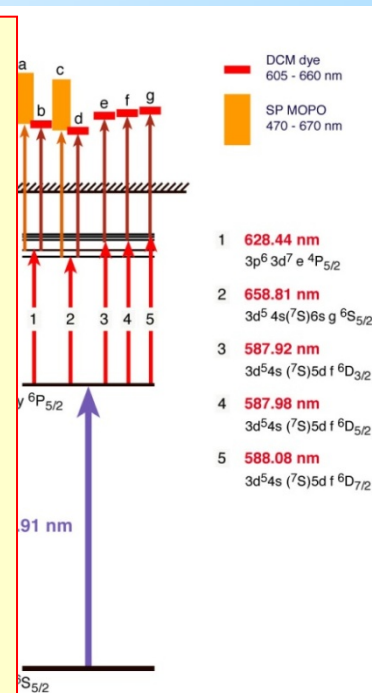
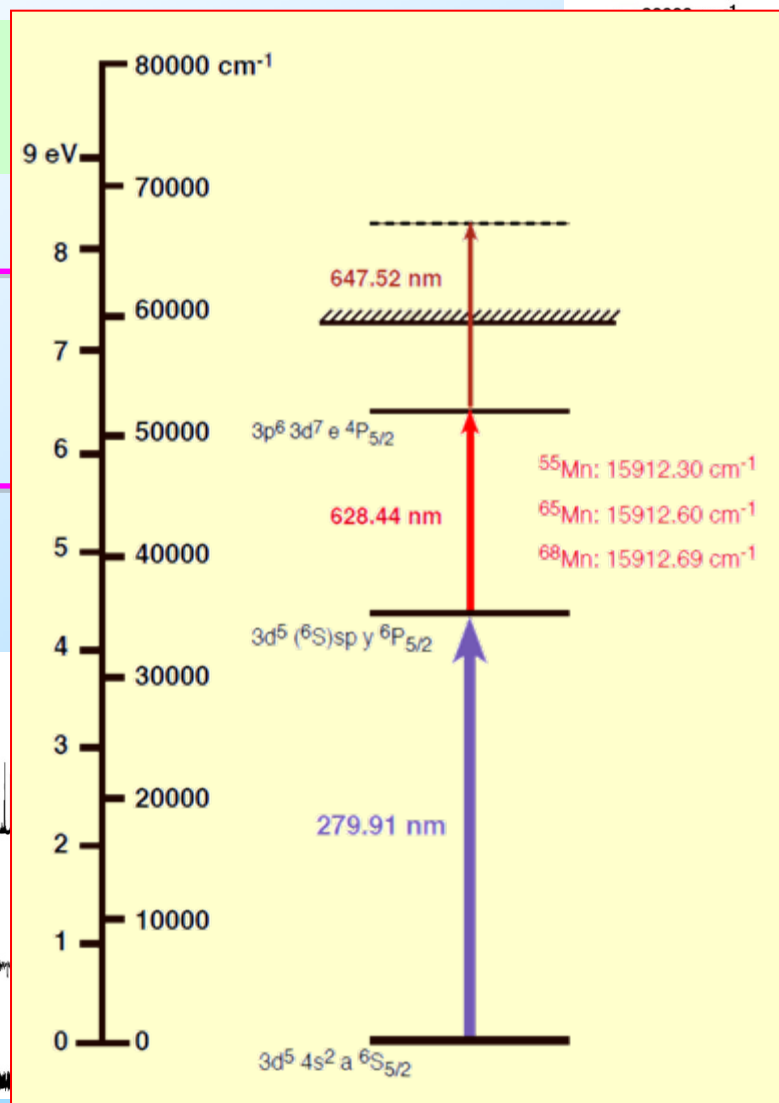


## Outcome of RIS study of Mn at LARIS:

Many new auto-ionizing states found

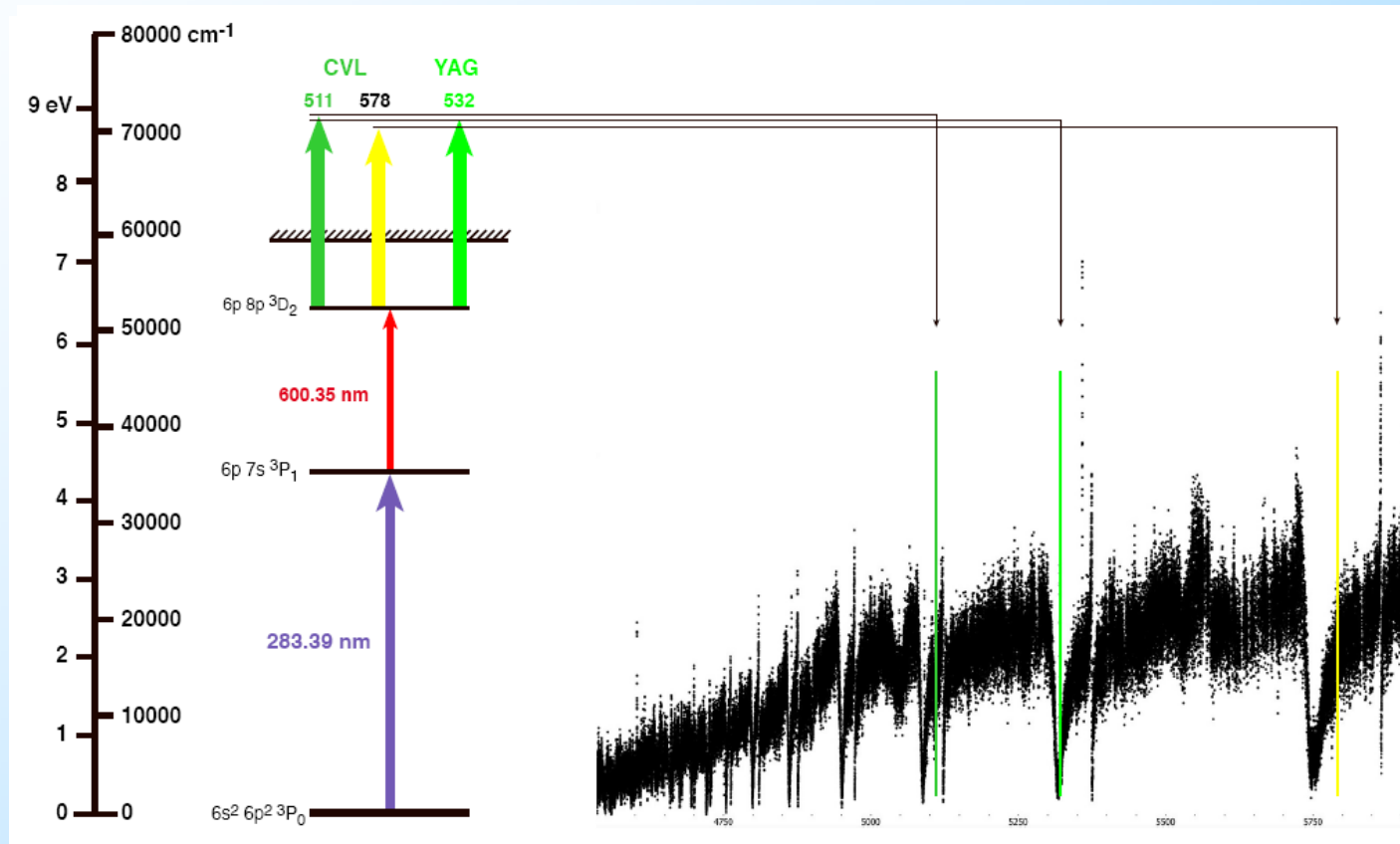
Various promising Nd:YAG based schemes tested

New scheme applied at RILIS  
Efficiency > 8 %



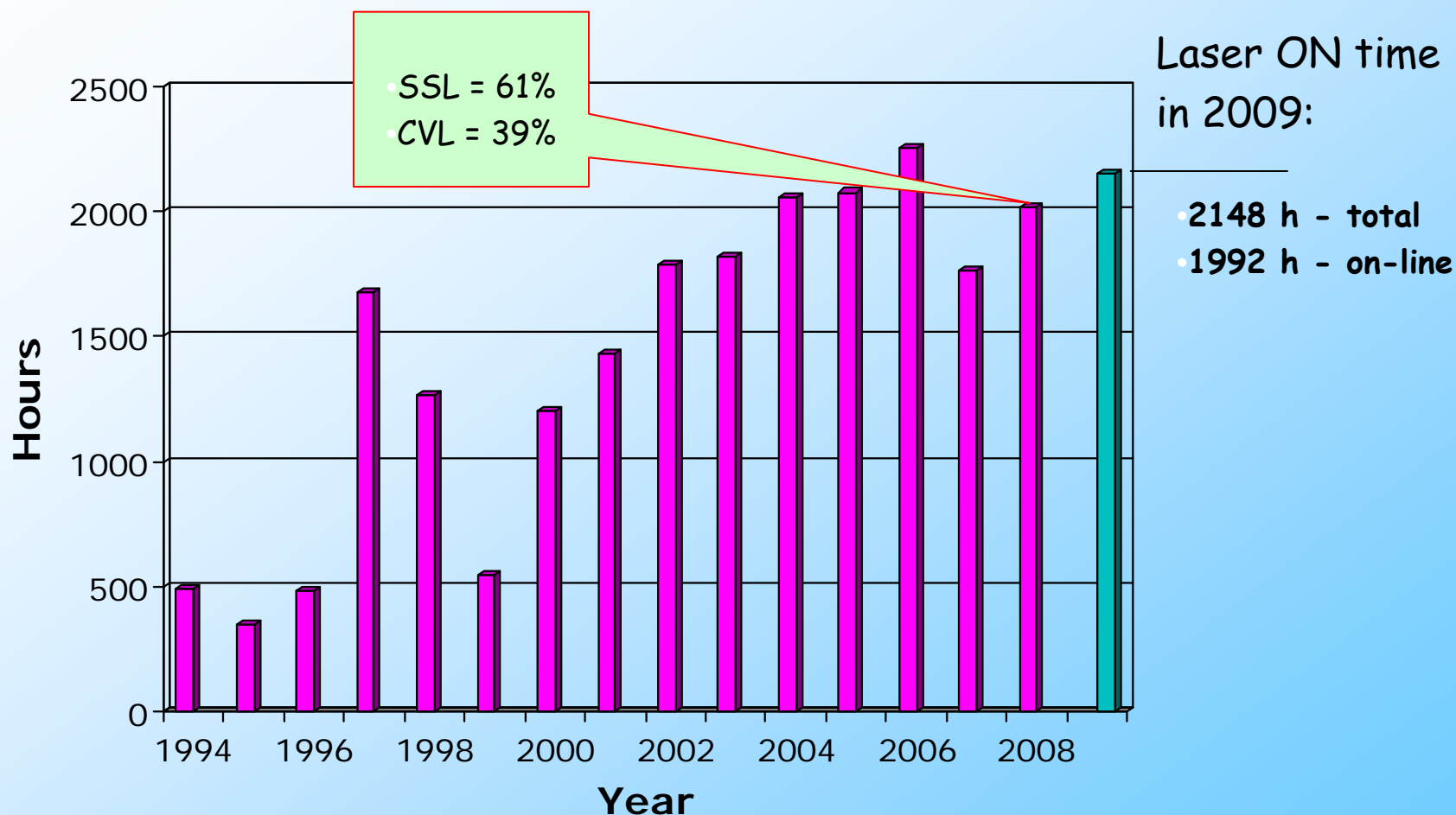
# LARIS result - Pb scheme test

- Check performance of 532 nm final step compared to CVL beams



- For the current RILIS scheme, the 532 nm YAG wavelength falls in the trough of a Rydberg/continuum interference (Fano) profile.
- The 511 nm and 578 nm CVL wavelengths are more efficient.
- An alternative RILIS second step gives access to a flat continuum region with the 532 nm YAG beam.

# RILIS operation in 1994-2009



In 2009 Nd:YAG lasers have been used for ALL 14 RILIS runs

Be, Ga, Ag, Nd, Po, Mn, Mg,  
Po, Sn, Mg, Mn, Be, Zn, Ni

# Comparison of isotope yields

Element	Isotope	Measured with CVL	Measured with Nd:YAG	Ratio YAG/CVL
Be	7	1.40E+10	4.00E+10	2.9
	11	7.00E+06	2.00E+07	2.9
Mg	29	1.60E+06	5.00E+06	3.1
	32	3.00E+04	1.80E+05	6.0
Ni	65	7.00E+07	4.90E+07	0.7
	66	1.00E+08	7.08E+07	0.7
Cu	69	1.80E+08	3.50E+07	0.2
	75	1.50E+05	4.80E+04	0.3
Zn	77	8.00E+05	2.50E+05	0.3
	80	3.00E+04	1.00E+04	0.3
Ga	73	2.80E+08	2.00E+09	7.1
	83	4.50E+03	6.50E+04	14.4
Mn	61	3.50E+06	4.30E+06	1.2
	63	1.00E+05	9.00E+04	0.9
Pb	188	1.70E+06	1.30E+06	0.8
	192	4.00E+07	4.00E+07	1.0
Po	202	1.70E+07	8.00E+07	4.7

*Extracted from ISOLDE e-logbooks*

# Closer to hardware limits

- Damage of non-linear crystals:

Third harmonics BBO damaged by UV

- 213 nm,  $\lambda_1$  for Zn,
- 70 mW

- Degradation of laser dyes:

Lifetime of Styryl 9 < 8 hours

- 823 nm,  $\lambda_3$  for Sn,
- 5 W from 22W pump

Bigger quantities of dye solutions are needed for RILIS runs with new pump lasers

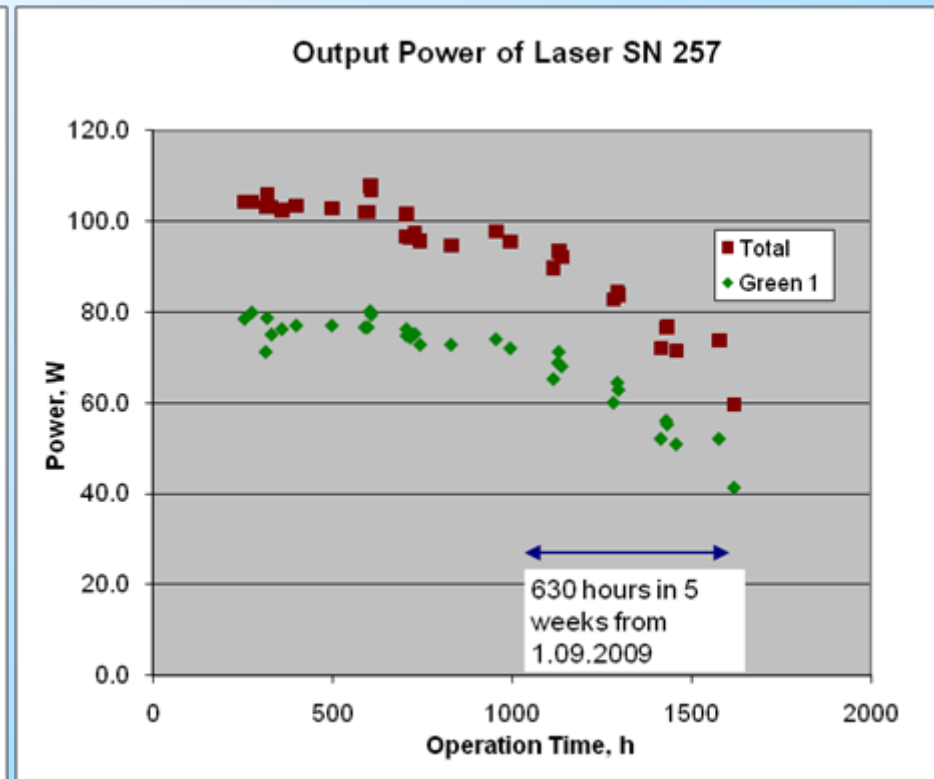
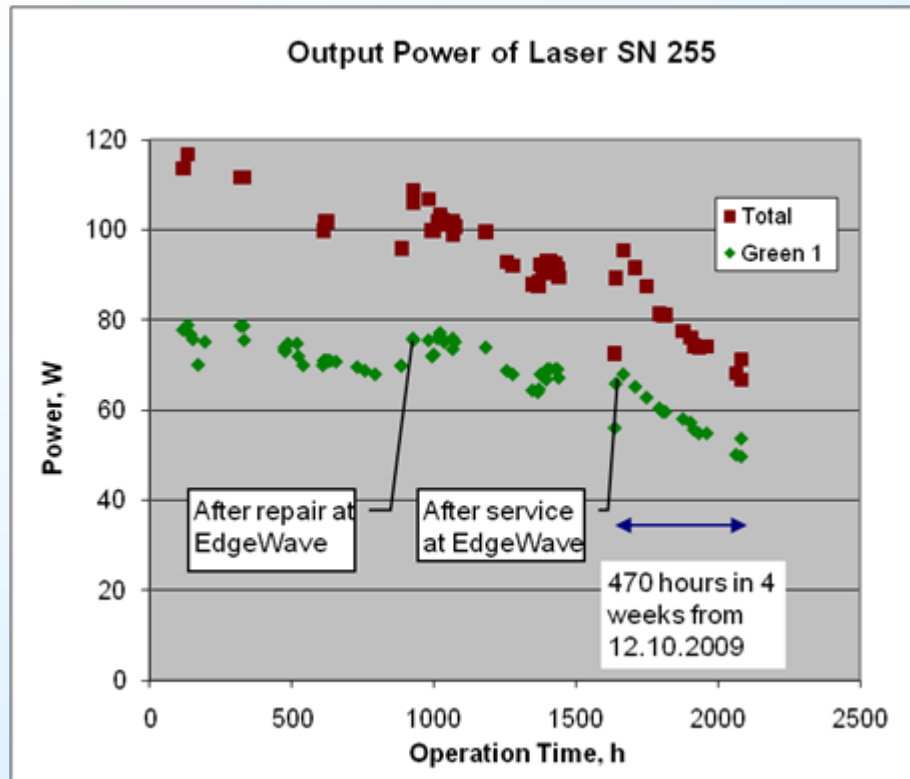


Dye laser power had to be reduced to avoid crystal damage



# Long-term laser power drift

In September - November lasers were running > 70% of time



The reason of power reduction is under investigation:

- Cooling efficiency dropped ?
- Optics contamination or damage ?
- Ageing of pumping diodes ?



# RILIS after CVL-YAG transition

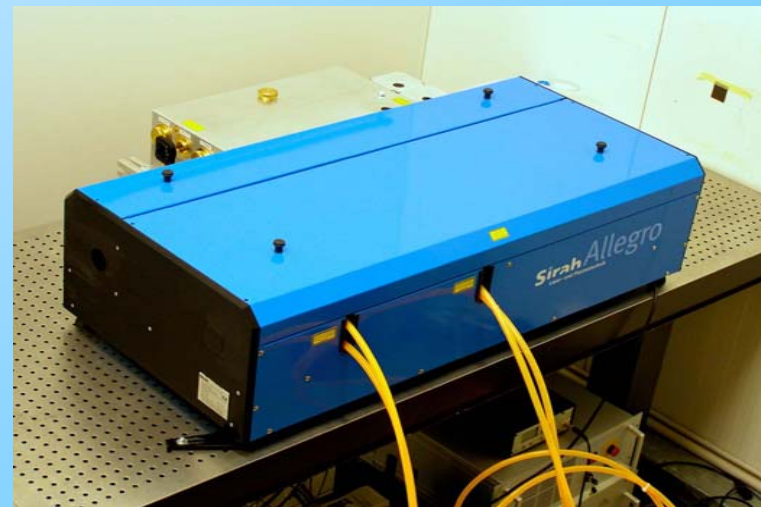
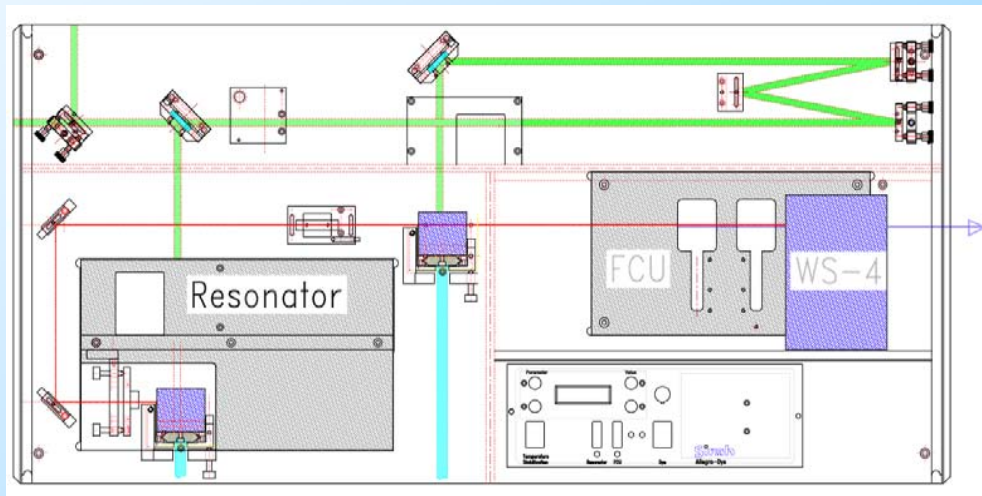
- More laser power -> higher ionization efficiency
  - High stability of SSL power -> ion current stability much better
  - Time from cold start of SSL to nominal operation ~ 30 min.
  - No electromagnetic noise to experimental hall from RILIS
  - New ionization scheme of Mn is developed
  - CVLs can be removed from laser cabin
- 
- SSL alignment and repair is possible only at EdgeWave
  - UV power is limited by the optical resistance of harmonics crystals
  - Efficiency of dye lasers is reduced due to shorter pump pulse
  - Lifetime of dyes is reduced
  - Operation of dye lasers and harmonics generators still requires continuous supervision by laser specialists



# Next steps

- **Dye Laser Upgrade**
- **One narrow (1 GHz) and two broadband (15 GHz) lasers are ordered**
  - Improve beam quality, especially for UV beams
  - Increase harmonic generation efficiency
  - Improve UV pumping performance

Allegro (made by Sirah GmbH) dye laser with amplifier and frequency doubling unit pumped by EdgeWave laser running at 10kHz





# Next steps

- **Nd:YAG pumped Ti:Sa system**
- **An additional independent fully solid state RILIS laser system**
  - Reduction of the reliance on laser dyes.
  - Better coverage of the IR and blue spectral ranges
  - Dual RILIS system could enable simultaneous RILIS setup and operation.

- **Pump laser:** 2 X commercial PI Nd:YAG, 532 nm, 60 W at 10 kHz
- **Tunable lasers:** 3 single sided UMz Ti:Sapphire lasers
  - - frequency doubling, tripling and quadrupling
  - - computerized temporal and spectral control, 3 GHz, 30 ns
  - - specs: 3 - 5 W @ 690-980 nm, 1 W @ 350-470, 150 mW @ 200 – 315 nm

Construction and purchasing of elements is started  
(Sebastian Rothe, PhD student in Mainz Uni and CERN)

Space presently occupied by CVLs will be available for Ti:Sa system

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